Solid State Devices, Inc. 14701 Firestone Blvd * La Mirada, Ca 90638	SPD6638, SPD6642, SPD6643 SERIES
Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com Designer's Data Sheet Part Number/Ordering Information ^{1/} SPD	300 mA 50 - 125 VOLTS 4.5 - 6.0 nsec Hyper Fast Recovery RECTIFIER
$ \begin{array}{c} $	 FEATURES: Hyper Fast Reverse Recovery Time 4.5 - 6 ns Max Hermetically Sealed Planar Passivated Chip For High Efficiency Applications Available in Axial & Subminiature Square Tab Versions TX, TXV, and S-Level Screening Available^{2/} Replacement for 1N6638, 1N6642, 1N6643 Low Thermal Resistance Metallurgical Class 3 Bond

MAXIMUM RATINGS ^{3/}				
RATING		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage DC Blocking Voltage	SPD6638 SPD6642 SPD6643	V _{RWM} V _R	125 75 50	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, Tc = 25°C)		lo	300	mAmps
Peak Surge Current (8.3 msec Pulse, Half Sine Wave Superimposed on Io, allow equilibrium between pulses, $T_c = 25^{\circ}C$)	junction to reach	I _{FSM}	2.5	Amps
Operating & Storage Temperature		T _{OP} and T _{STG}	-65 to +175	°C
Thermal Resistance SMS- Junc Axial- Junction t	tion to End Tab o Lead @ .375"	R₀ _{JE} R₀ _{JL}	65 220	°C/W

NOTES:

1/ For Ordering Information, Price, and Availability- Contact Factory.

 $\underline{\textbf{2}}$ / Screening Based on MIL-PRF-19500. Screening Flows Available on Request.

 $\underline{3}\prime$ Unless Otherwise Specified, All Electrical Characteristics @25°C.

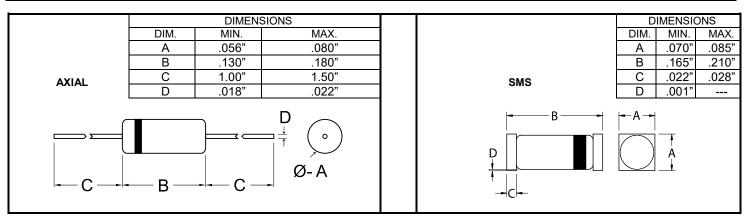




SPD6638, SPD6642, SPD6643 **SERIES**

ELECTRICAL CHARACTERISTICS 3/

CHARACTERISTICS		SYMBOL	VALUE	UNIT
Maximum Instantaneous Forward Voltage Drop (Pulsed, $T_A = 25^{\circ}C$)	SPD6638 @ I⊧ = 10mA SPD6642 @ I⊧ = 10mA SPD6643 @ I⊧ = 10mA	V _{F1}	0.8 0.8 1.0	Vdc
	SPD6638 @ I _F = 200mA SPD6642 @ I _F = 100mA SPD6643 @ I _F = 100mA	V _{F2}	1.1 1.2 1.2	Vdc
Maximum Instantaneous Forward Voltage Drop (Pulsed)	I _F = 100mA, T _A = -55°C	VF3	1.3	Vdc
Minimum Breakdown Voltage Ir = 100 μA	SPD6638 SPD6642 SPD6643	BvR	125 100 75	Vdc
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T _A = 25°C)	SPD6638 @ V _R = 20V SPD6642 @ V _R = 20V SPD6643 @ V _R = 20V	I _{R1}	35 25 50	nA
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T _A = 25°C)	SPD6638 @ V _R = 100V SPD6642 @ V _R = 75V SPD6643 @ V _R = 50V	I _{R2}	500 500 500	nA
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T _A = 150°C)	SPD6638 @ V _R = 20V SPD6642 @ V _R = 20V SPD6643 @ V _R = 20V	I _{R3}	50 50 75	μA
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T _A = 150°C)	SPD6638 @ V _R = 100V SPD6642 @ V _R = 75V SPD6643 @ V _R = 50V	I _{R4}	100 100 160	μA
Maximum Junction Capacitance ($T_A = 25^{\circ}C$, f = 1MHz) V _R = 0V	SPD6638 SPD6642 SPD6643	CJ1	2.5 5.0 5.0	pf
Maximum Junction Capacitance ($T_A = 25^{\circ}C$, f = 1MHz) V _R = 1.5V	SPD6638 SPD6642 SPD6643	C _{J2}	2.0 2.8 2.8	pf
Maximum Reverse Recovery Time (I _F = I _R = 10 mA, I _{RR} = 1 mA)	SPD6638 SPD6642 SPD6643	trr	4.5 5.0 6.0	nsec



NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RH0004F	DOC
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